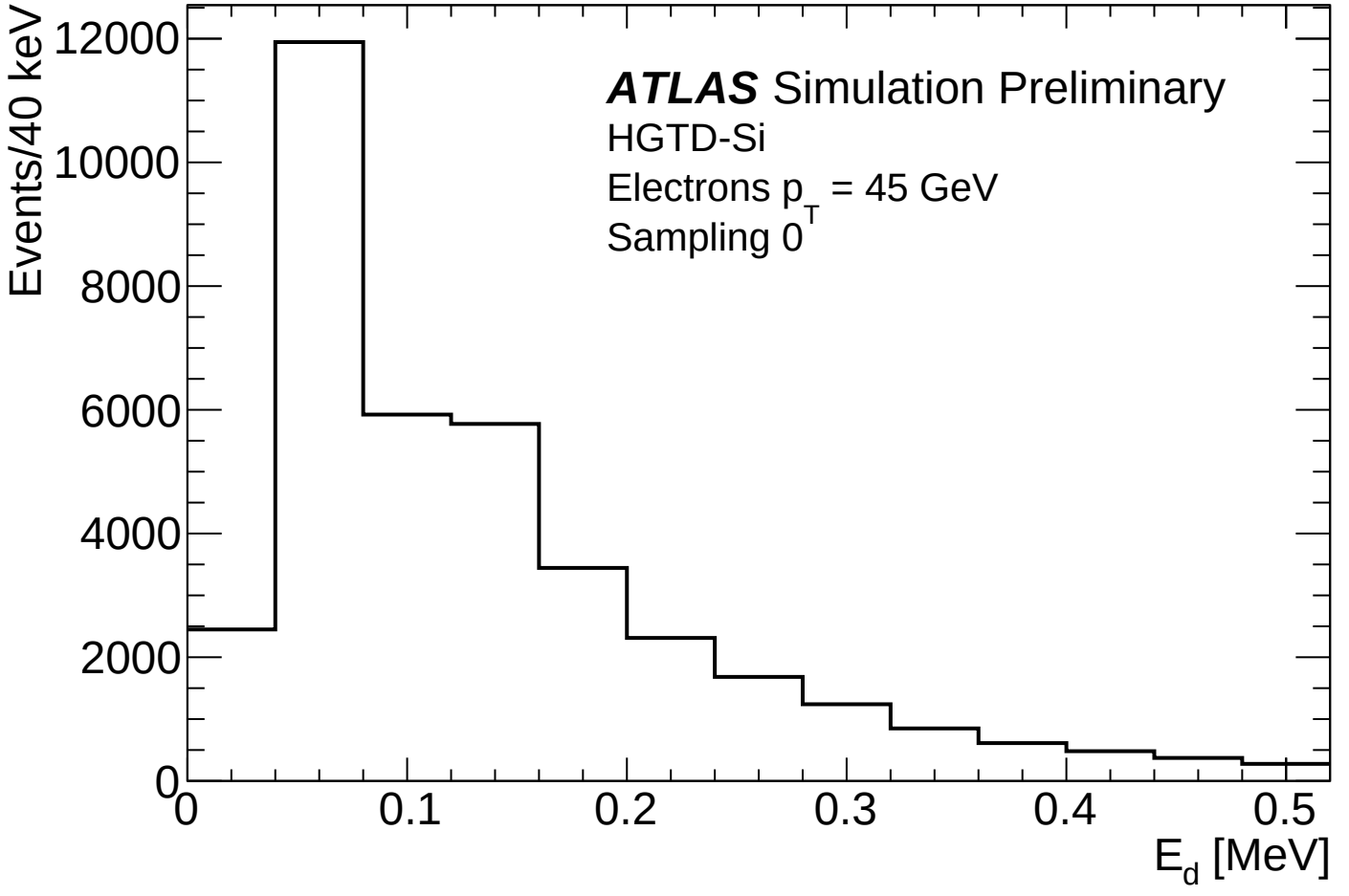
ATLAS Simulation Preliminary
HGTD-Si
Electrons p_T = 45 GeV
Sampling 0
Events/40 keV
12000
10000
8000
6000
4000
2000
0
0
0.1
0.2
0.3
0.4
0.5
E_d [MeV]